



2814
Image

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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of :
Han-Chao LAI ET AL : Confirmation No. 9082
U.S. Patent Application No. 09/888,494 : Group Art Unit: 2814
Filed: June 26, 2001 : Examiner: PHAM, LONG
For: METHOD FOR FORMING A METAL OXIDE SEMICONDUCTOR TYPE FIELD
EFFECT TRANSISTOR

RESPONSE

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

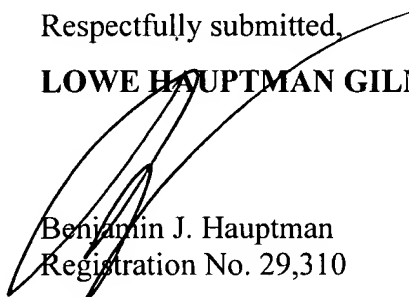
Sir:

In response to the Notice of Non-Compliant Amendment mailed October 14, 2003, and in confirmation of a telephone conference with Sandra Paris of the U.S. Patent Office, it is the undersigned's understanding that no response is required to this communication since no amendments to the specification or claims were made in the Response filed October 1, 2003.

Accordingly, the Notice of Non-Compliant Amendment should be withdrawn.

Respectfully submitted,

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BJH/jk